## nexperia

## **Quarterly Reliability Monitoring Results**

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier		User Part Number						
Nexperia B.V. Name of Laboratory Assembly reliability labs Based on AEC-Q101 Test		PDTA115EM						
		Part Description						
		Nexperia DHAM Small Signal Bipolar Transistor						
		MCD package						
		Test Conditions	Duration	# Lots	# Quantity	# Rejects		
	TEST							
	Pre- and Post-Stress							
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
		JESD22-A113	241					
	PC	Bake Tamb = 125 °C Soak Tamb = 85 °C, RH = 85%	24 hours 168 hours					
# A1	Preconditioning	Reflow soldering	3 cycles	208	16640	0		
<i>π</i> A1		MIL-STD-750-1	2 0,000	200	10040	U		
	HTRB	MIL-STD-750-1 M1039 Method A						
		Tj = Tjmax, Vr = $100\%$ of max. datasheet						
# B1	Bias	reverse voltage	1000 hours	202	16160	0		
	тс	JESD22-A104						
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	52	4160	0		
		JESD22-A102						
	AC	Tamb = 121 °C, RH = 100 %						
# A3 alt	Autoclave	Pressure = 205 kPa (29.7 psia)	96 hours	52	4160	0		
	H3TRB	JESD22-A101						
	High Humidity High	Tamb = 85 °C, RH = 85%, VR = 80 % of						
# A2 alt	Temperature Reverse Bias		1000 hours	52	4160	0		
		MIL-STD-750 Method 1037						
	IOL Intermittent Operating Life	ton = toff, devices powered to insure $\Delta Tj$ =	10001	50				
# A5	Intermittent Operating Life		1000 hours	52	4160	0		
	RSH	JESD22-A111						
# C8	Resistance to Solder Heat		10 c					
# C0	SD	200 0 = 5 0	10 s	n.a.	n.a.	n.a.		
# C10	Solderability	J-STD-002		111	1110	0		
# CIU	Solderability	5 515 002		111	1110	U		

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia DHAM	Small Signal Bipolar Transistor	16160	0	0.26	3.81E+09

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